NSN 5961-00-850-8030

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Inclosure Material:

Metal

Overall Length:

0.230 inches

Terminal Length:

1.500 inches

Overall Diameter:

0.330 inches

Internal Configuration:

Junction contact

Internal Junction Configuration:

Pnp

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Germanium

Voltage Rating In Volts Per Characteristic:

45.0 breakdown voltage, collector-to-base, emitter open and 30.0 breakdown voltage, collector-to-emitter, with specified resistance

between base and emitter and 30.0 breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

500.00 milliamperes source cutoff current

Power Rating Per Characteristic:

200.0 milliwatts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

70.0 degrees celsius ambient air

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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